

TECHNICAL DATA  
DATA SHEET 1057, REV. -

## HERMETIC POWER SCHOTTKY RECTIFIER

**DESCRIPTION:** A 30 VOLT, 120 AMP, HERMETIC POWER SCHOTTKY RECTIFIER IN A SHD-3/3A/3B PACKAGE.

### MAXIMUM RATINGS

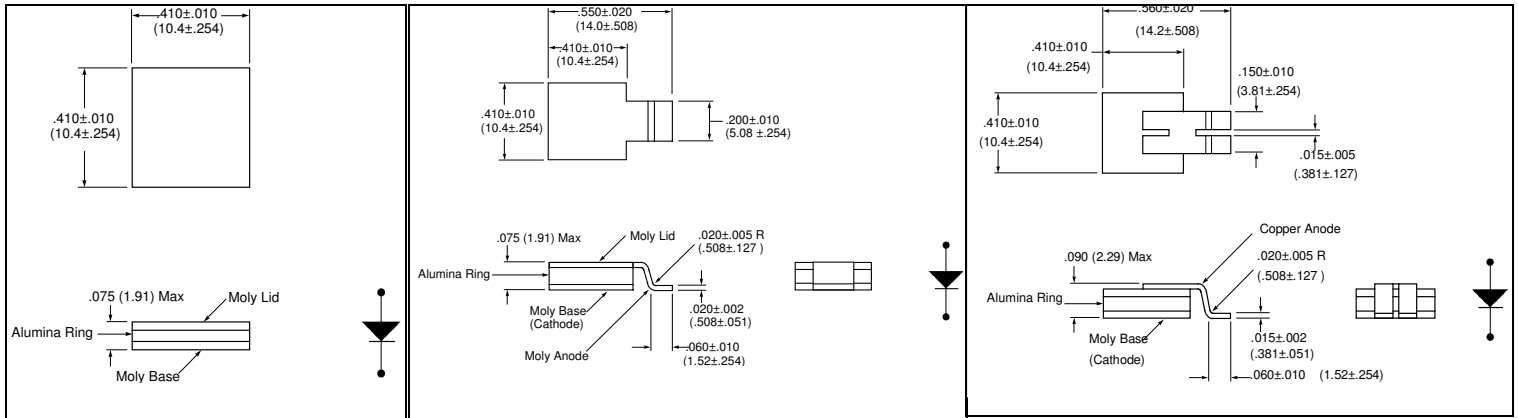
ALL RATINGS ARE @  $T_C = 25^\circ\text{C}$  UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	30	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$ )	$I_O$	120	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ( $t=10\text{ms}$ , Sine)	$I_{FSM}$	1650	Amps
MAXIMUM JUNCTION CAPACITANCE ( $V_r=5\text{V}$ )	$C_T$	6600	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.20	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 150	$^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ( $I_f = 120$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$V_f$	0.53 0.43	Volts
MAXIMUM REVERSE CURRENT ( $I_r$ @ 30 V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$I_r$	12 600	mA

**MECHANICAL DIMENSIONS: In Inches / mm**



**SHD-3**

**SHD-3A**

**SHD-3B**

**TECHNICAL DATA**

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